

COS/MOS INTEGRATED CIRCUITS

S G S-THOMSON 07C D

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HCC/HCF 4070B
HCC/HCF 4077B

41C 08872 0 T-43-21

4070B - QUAD EXCLUSIVE-OR GATE 4077B - QUAD EXCLUSIVE-NOR GATE

- MEDIUM-SPEED OPERATION $t_{PHL} = t_{PLH} = 70$ ns (TYP.) AT $V_{CC} = 10V$, $C_L = 50$ pF
- QUIESCENT CURRENT SPECIFIED TO 20V FOR HCC DEVICE
- 5V, 10V AND 15V PARAMETRIC RATING
- INPUT CURRENT OF 100 nA AT 18V AND 25°C FOR HCC DEVICE
- 100% TESTED FOR QUIESCENT CURRENT
- MEETS ALL REQUIREMENTS OF JEDEC TENTATIVE STANDARD No. 13A, "STANDARD SPECIFICATIONS FOR DESCRIPTION OF "B" SERIES CMOS DEVICES"

The HCC 4070B/4077B (extended temperature range) and HCF 4070B/4077B (intermediate temperature range) are monolithic integrated circuits, available in 14-lead dual in-line plastic or ceramic package, ceramic flat package and plastic micropackage.

The HCC/HCF 4070B contains four independent exclusive-OR gates.

The HCC/HCF 4077B contains four independent exclusive-NOR gates.

The HCC/HCF 4070B and HCC/HCF 4077B provide the system designer with a means for direct implementation of the exclusive-OR and exclusive-NOR function, respectively. For applications as Logical comparators, Adders/subtractors, Parity generators and checkers.

ABSOLUTE MAXIMUM RATINGS

V_{DD}^*	Supply voltage: HCC types HCF types	-0.5 to 20 -0.5 to 18	V V
V_I	Input voltage	-0.5 to $V_{DD} + 0.5$	V
I_I	DC input current (any one input)	± 10	mA
P_{tot}	Total power dissipation (per package) Dissipation per output transistor for T_{op} = full package-temperature range	200 100	mW mW
T_{op}	Operating temperature: HCC types HCF types	-55 to 125 -40 to 85	°C °C
T_{stg}	Storage temperature	-65 to 150	°C

* All voltage values are referred to V_{SS} pin voltage

ORDERING NUMBERS:

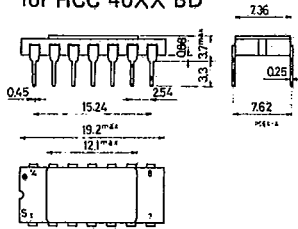
- HCC 40XX BD for dual in-line ceramic package
- HCC 40XX BF for dual in-line ceramic package, frit seal
- HCC 40XX BK for ceramic flat package
- HCF 40XX BE for dual in-line plastic package
- HCF 40XX BF for dual in-line ceramic package, frit seal
- HCF 40XX BM for plastic micropackage

HCC/HCF 4070B
HCC/HCF 4077B

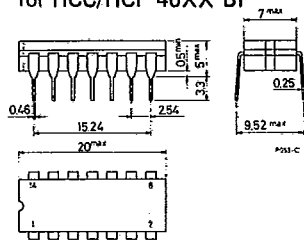
41C 08873 DT-43-21

MECHANICAL DATA (dimensions in mm)

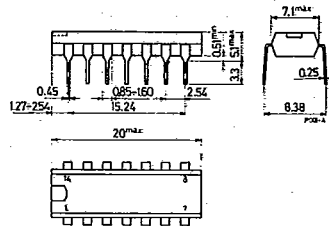
Dual in-line ceramic package for HCC 40XX BD



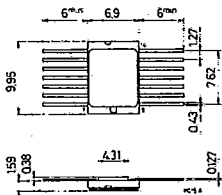
Dual in-line ceramic package for HCC/HCF 40XX BF



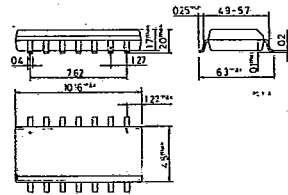
Dual in-line plastic package for HCF 40XX BE



Ceramic flat package for HCC 40XX BK

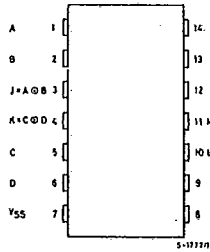


Plastic micropackage for HCF 40XX BM

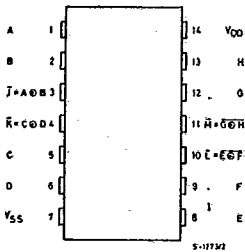


CONNECTION DIAGRAMS

for 4070B



for 4077B



TRUTH TABLES (1 of 4 gates)

for 4070B

A	B	J
0	0	0
1	0	1
0	1	1
1	1	0

Where 1 = High level
0 = Low level
J = A ⊕ B

for 4077B

A	B	J
0	0	1
1	0	0
0	1	0
1	1	1

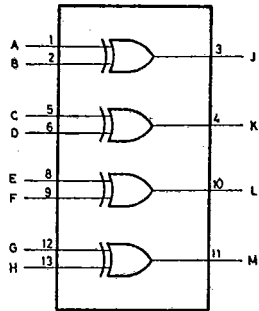
Where 1 = High level
0 = Low level
J = A ⊕ B



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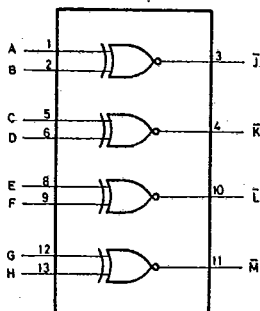
FUNCTIONAL DIAGRAMS

for 4070B

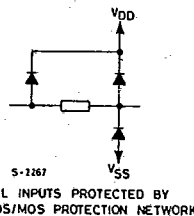


J = A \bar{B} , K = C \bar{D} , L = E \bar{F} , M = G \bar{H}
 $V_{SS} = 7$, $V_{DD} = 14$
 S-1770/1

for 4077B

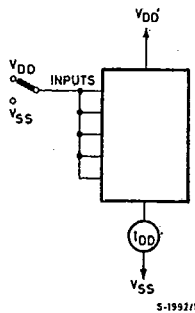


J-bar = A \bar{B} , K-bar = C \bar{D} , L-bar = E \bar{F} , M-bar = G \bar{H}
 $V_{SS} = 7$, $V_{DD} = 14$
 S-1771/1

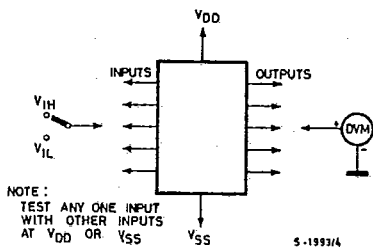


TEST CIRCUIT

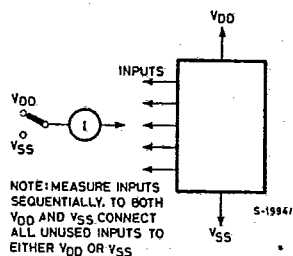
Quiescent device current



Input voltage



Input leakage current



RECOMMENDED OPERATING CONDITIONS

V_{DD}	Supply voltage: HCC types HCF types	3 to 18 V 3 to 15 V
V_I	Input voltage	0 to V_{DD} V
T_{op}	Operating temperature: HCC types HCF types	-55 to 125 °C -40 to 85 °C



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STATIC ELECTRICAL CHARACTERISTICS (over recommended operating conditions)

Parameter		Test conditions				Values						Unit		
		V _I (V)	V _O (V)	I _O (μA)	V _{DD} (V)	T _{Low} *		25°C			T _{High} *			
						Min.	Max.	Min.	Typ.	Max.	Min.		Max.	
I _L	Quiescent current	HCC types	0/ 5			5		1		0.02	1		30	μA
			0/10			10		2		0.02	2		60	
			0/15			15		4		0.02	4		120	
		HCF types	0/ 5			5		4		0.02	4		30	
			0/10			10		8		0.02	8		60	
			0/15			15		16		0.02	16		120	
V _{OH}	Output high voltage	0/ 5		< 1	5	4.95		4.95			4.95		V	
		0/10		< 1	10	9.95		9.95			9.95			
		0/15		< 1	15	14.95		14.95			14.95			
V _{OL}	Output low voltage	5/0		< 1	5		0.05			0.05		0.05	V	
		10/0		< 1	10		0.05			0.05		0.05		
		15/0		< 1	15		0.05			0.05		0.05		
V _{IH}	Input high voltage		0.5/4.5	< 1	5	3.5		3.5			3.5		V	
			1/9	< 1	10	7		7			7			
			1.5/13.5	< 1	15	11		11			11			
V _{IL}	Input low voltage		4.5/0.5	< 1	5		1.5			1.5		1.5	V	
			9/1	< 1	10		3			3		3		
			13.5/1.5	< 1	15		4			4		4		
I _{OH}	Output drive current	HCC types	0/ 5	2.5		5	-2		-1.6	-3.2		-1.15	mA	
			0/ 5	4.6		5	-0.64		-0.51	-1		-0.36		
			0/10	9.5		10	-1.6		-1.3	-2.6		-0.9		
		HCF types	0/ 5	2.5		5	-1.53		-1.36	-3.2		-1.1		
			0/ 5	4.6		5	-0.52		-0.44	-1		-0.36		
			0/10	9.5		10	-1.3		-1.1	-2.6		-0.9		
I _{OL}	Output sink current	HCC types	0/ 5	0.4		5	0.64		0.51	1		0.36	mA	
			0/10	0.5		10	1.6		1.3	2.6		0.9		
			0/15	1.5		15	4.2		3.4	6.8		2.4		
		HCF types	0/ 5	0.4		5	0.52		0.44	1		0.36		
			0/10	0.5		10	1.3		1.1	2.6		0.9		
			0/15	1.5		15	3.6		3.0	6.8		2.4		
I _{IH} , I _{IL}	Input leakage current	HCC types	0/18	Any input	18		±0.1		±10 ⁻⁵	±0.1		± 1	μA	
		HCF types	0/15		15		±0.3		±10 ⁻⁵	±0.3		± 1		
C _I	Input capacitance			.Any input					5	7.5		pF		

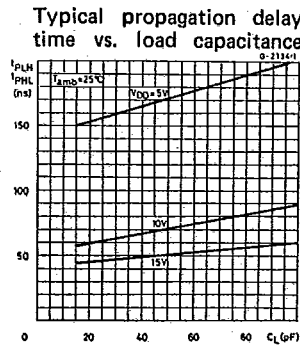
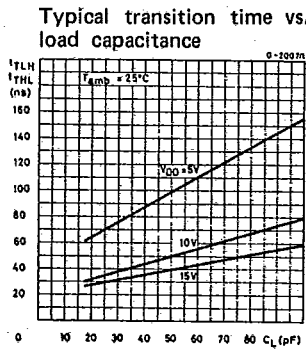
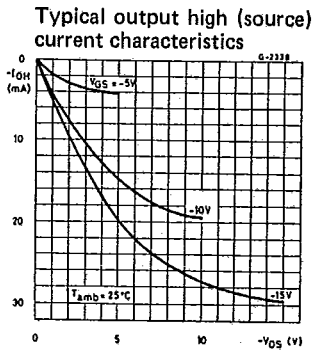
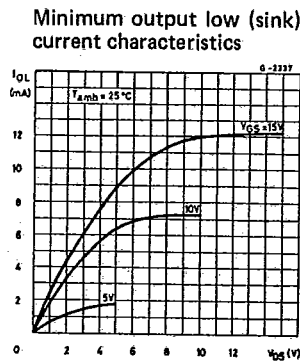
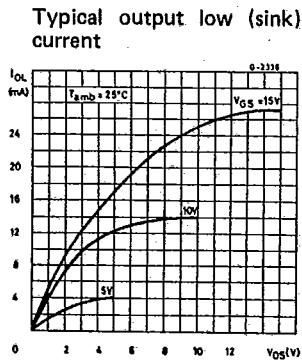
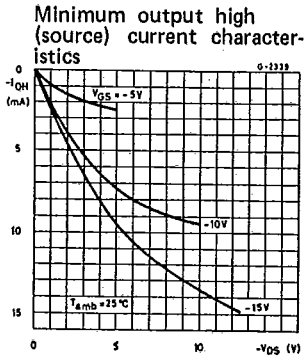
* T_{Low} = - 55°C for HCC device; -40°C for HCF device.
 * T_{High} = +125°C for HCC device; +85°C for HCF device.
 The Noise Margin for both "1" and "0" level is: 1V min. with V_{DD}= 5V
 2V min. with V_{DD}= 10V
 2.5V min. with V_{DD}= 15V



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DYNAMIC ELECTRICAL CHARACTERISTICS ($T_{amb} = 25^{\circ}C$, $C_L = 50$ pF, $R_L = 200$ k Ω , typical temperature coefficient for all V_{DD} values is 0.3%/ $^{\circ}C$, all input rise and fall times = 20 ns)

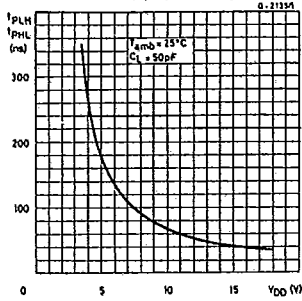
Parameter	Test conditions	Values			Unit	
		$V_{CC}(V)$	Min.	Typ.		Max.
t_{PHL} , Propagation delay time t_{PLH}		5		140	280	ns
		10		65	130	
		15		50	100	
t_{THL} , Transition time t_{TLH}		5		100	200	ns
		10		50	100	
		15		40	80	



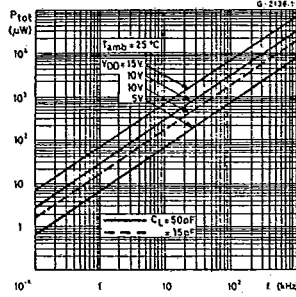
HCC/HCF 4070B
HCC/HCF 4077B

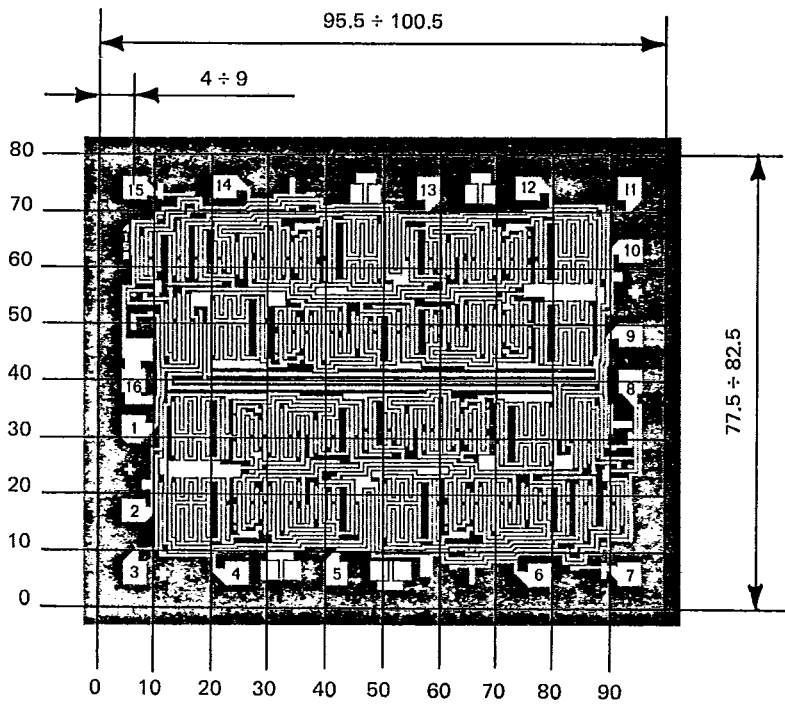
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Typical propagation delay time vs. supply voltage

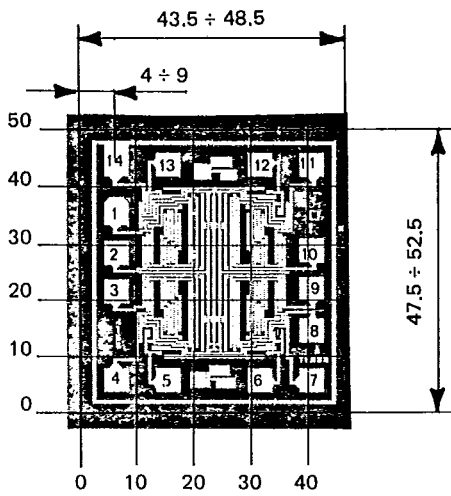


Typical dynamic power dissipation vs. input frequency





4015B



4016B